TOSHIBA Transistor Silicon NPN Epitaxial Type

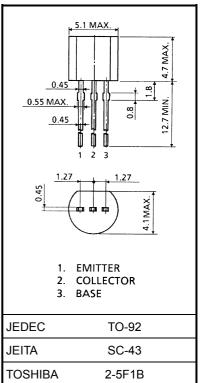
2SC2878

For Muting and Switching Applications

- High emitter-base voltage: $V_{EBO} = 25 V (min)$
- High reverse hFE: Reverse hFE = 150 (typ.) (V_{CE} = -2 V, I_C = -4 mA)
- Low on resistance: $RON = 1 \Omega$ (typ.) (IB = 5 mA)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	50	V
Collector-emitter voltage	V _{CEO}	20	V
Emitter-base voltage	V _{EBO}	25	V
Collector current	Ι _C	300	mA
Base current	Ι _Β	60	mA
Collector power dissipation	P _C	400	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C



Weight: 0.21 g (typ.)

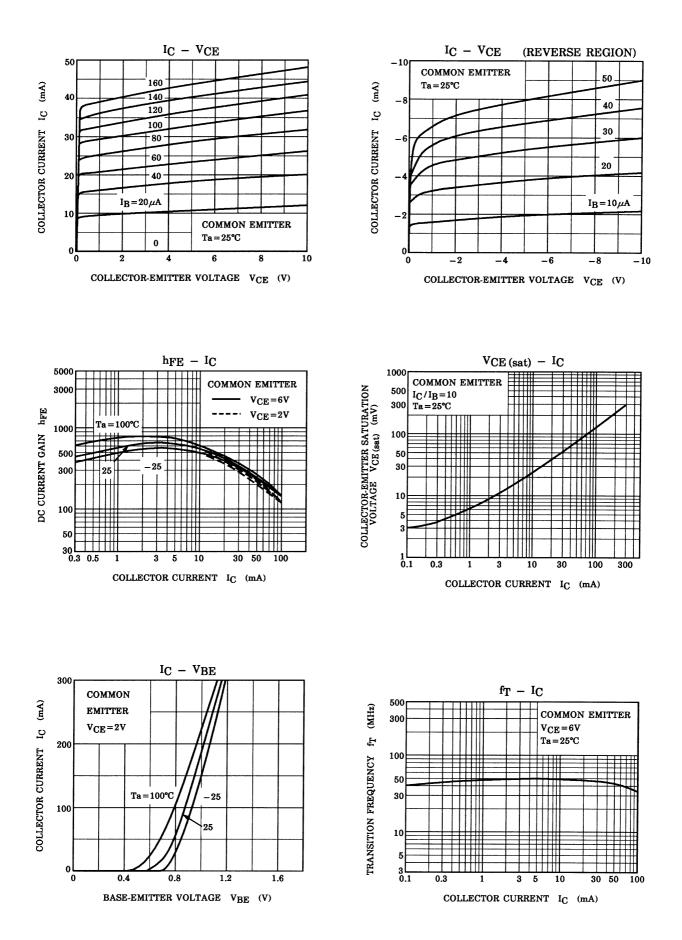
Electrical Characteristics (Ta = 25°C)

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off	current	I _{CBO}	$V_{CB} = 50 \text{ V}, \text{ I}_{E} = 0$	_		0.1	μA
Emitter cut-off cu	rrent	I _{EBO}	$V_{EB} = 25 \text{ V}, \text{ I}_{C} = 0$		_	0.1	μA
DC current gain		h _{FE} (Note)	$V_{CE} = 2 V$, $I_C = 4 mA$	200		1200	
Collector-emitter	saturation voltage	V _{CE (sat)}	$I_C = 30 \text{ mA}, I_B = 3 \text{ mA}$		0.042	0.1	V
Base-emitter volt	age	V _{BE}	$V_{CE} = 2 V$, $I_C = 4 mA$		0.61	_	V
Transition frequency		fT	$V_{CE} = 6 \text{ V}, I_C = 4 \text{ mA}$		30	_	MHz
Collector output capacitance		C _{ob}	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0, \text{ f} = 1 \text{ MHz}$		4.8	7	pF
Switching time	Turn-on time	t _{on}	$10V \prod_{\alpha \neq s} VBB VCC = -3V = 12V$	_	160	_	
	Storage time	t _{stg}		_	500	_	ns
	Fall time	t _f			130	_	

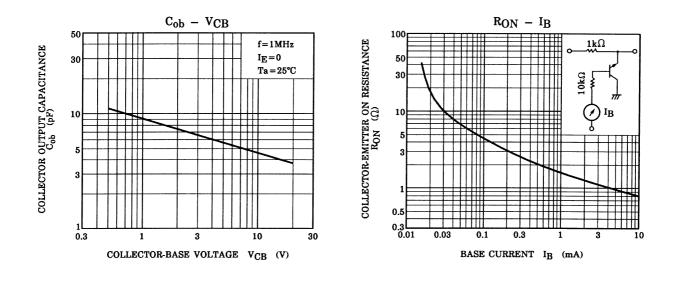
Note: hFE classification A: 200~700, B: 350~1200

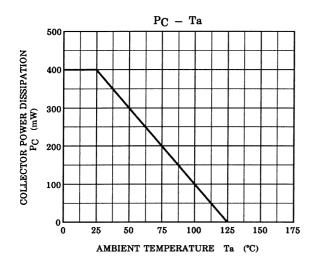
Unit: mm

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